

HA-4741/883

July 1994

Quad Operational Amplifier

Features

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- Slew Rate 0.9V/ μ s (Min)
- Bandwidth 2.5MHz (Min)
- Input Offset Voltage..... 3mV (Max)
- Input Bias Current 200nA (Max)
- Input Voltage Noise 9nV/ $\sqrt{\text{Hz}}$ (Typ)
- No Crossover Distortion
- Standard Quad Pinout

Applications

- Universal Active Filters
- D3 Communications Filters
- Audio Amplifiers
- Battery-Powered Equipment

Description

The Intersil HA-4741/883, which contains four amplifiers on a monolithic chip, provides a new measure of performance for general purpose operational amplifiers. Each amplifier in the HA-4741/883 has operating specifications that equal or exceed those of the 741-type amplifier in all categories of performance.

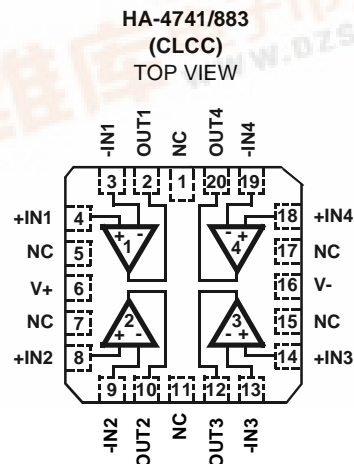
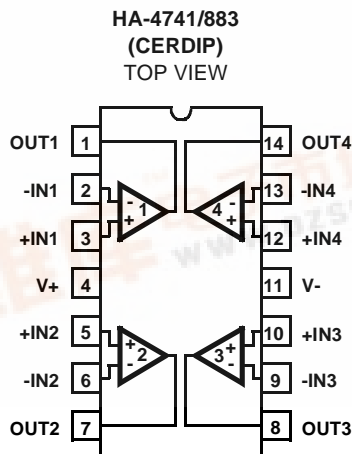
The HA-4741/883 is well suited to applications requiring accurate signal processing by virtue of its low values of input offset voltage (3mV max), input bias current (200nA max) and input voltage noise (9nV/ $\sqrt{\text{Hz}}$ typ at 1kHz). The 2.5MHz bandwidth, coupled with high open loop gain, allow the HA-4741/883 to be used in designs requiring amplifiers of wideband signals, such as audio amplifiers. Audio application is further enhanced by the HA-4741/883's negligible output crossover distortion. These excellent dynamic characteristics also make the HA-4741/883 ideal for a wide range of active filter designs. Performance integrity of multi-channel designs is assured by a high level of amplifier-to-amplifier isolation (66dB at 10kHz).

A wide range of supply voltages ($\pm 2\text{V}$ to $\pm 20\text{V}$) can be used to power the HA-4741/883, making it compatible with almost any system including battery-powered equipment.

Ordering Information

| PART NUMBER | TEMPERATURE RANGE | PACKAGE |
|--------------|-------------------|---------------------|
| HA1-4741/883 | -55°C to +125°C | 14 Lead CerDIP |
| HA4-4741/883 | -55°C to +125°C | 20 Lead Ceramic LCC |

Pinouts



Specifications HA-4741/883

Absolute Maximum Ratings

| | |
|----------------------------------------|-------------------------------------------|
| Voltage Between V+ and V- Terminals | 40V |
| Differential Input Voltage | 15V |
| Voltage at Either Input Terminal | V+ to V- |
| Output Current | Indefinite (One Amplifier Shorted to GND) |
| Junction Temperature (T _J) | +175°C |
| Storage Temperature Range | -65°C to +150°C |
| ESD Rating | <2000V |
| Lead Temperature (Soldering 10s) | +300°C |

Thermal Information

| | | |
|----------------------------------------------------------------------|---------------|---------------|
| Thermal Resistance | θ_{JA} | θ_{JC} |
| CerDIP Package | 75°C/W | 20°C/W |
| Ceramic LCC Package | 65°C/W | 15°C/W |
| Package Power Dissipation Limit at +75°C for T _J ≤ +175°C | | |
| CerDIP Package | 1.33W | |
| Ceramic LCC Package | 1.54W | |
| Package Power Dissipation Derating Factor Above +75°C | | |
| CerDIP Package | 13.3mW/°C | |
| Ceramic LCC Package | 15.4mW/°C | |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Operating Conditions

| | | |
|-----------------------------|-----------------|-------------------------------|
| Operating Temperature Range | -55°C to +125°C | $V_{INCM} \leq 1/2 (V+ - V-)$ |
| Operating Supply Voltage | ±5V to ±15V | $R_L \geq 2k\Omega$ |

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Tested at: V_{SUPPLY} = ±15V, R_{SOURCE} = 100Ω, R_{LOAD} = 500kΩ, V_{OUT} = 0V, Unless Otherwise Specified.

| PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUPS | TEMPERATURE | LIMITS | | UNITS |
|-----------------------------|-------------------|-----------------------------------------------------------------------------|-------------------|---------------|--------|-----|-------|
| | | | | | MIN | MAX | |
| Input Offset Voltage | V _{IO} | V _{CM} = 0V | 1 | +25°C | -3 | 3 | mV |
| | | | 2, 3 | +125°C, -55°C | -5 | 5 | mV |
| Input Bias Current | +I _B | V _{CM} = 0V, +R _S = 10kΩ, -R _S = 100Ω | 1 | +25°C | -200 | 200 | nA |
| | | | 2, 3 | +125°C, -55°C | -325 | 325 | nA |
| | -I _B | V _{CM} = 0V, +R _S = 100Ω, -R _S = 10kΩ | 1 | +25°C | -200 | 200 | nA |
| | | | 2, 3 | +125°C, -55°C | -325 | 325 | nA |
| Input Offset Current | I _{IO} | V _{CM} = 0V, +R _S = 10kΩ, -R _S = 10kΩ | 1 | +25°C | -30 | 30 | nA |
| | | | 2, 3 | +125°C, -55°C | -75 | 75 | nA |
| Common Mode Range | +CMR | V+ = 3V, V- = -27V | 1 | +25°C | 12 | - | V |
| | | | 2, 3 | +125°C, -55°C | 12 | - | V |
| | -CMR | V+ = 27V, V- = -3V | 1 | +25°C | - | -12 | V |
| | | | 2, 3 | +125°C, -55°C | - | -12 | V |
| Large Signal Voltage Gain | +A _{VOL} | V _{OUT} = 0V and +10V, R _L = 2kΩ | 4 | +25°C | 50 | - | kV/V |
| | | | 5, 6 | +125°C, -55°C | 25 | - | kV/V |
| | -A _{VOL} | V _{OUT} = 0V and -10V, R _L = 2kΩ | 4 | +25°C | 50 | - | kV/V |
| | | | 5, 6 | +125°C, -55°C | 25 | - | kV/V |
| Common Mode Rejection Ratio | +CMRR | ΔV _{CM} = -10V, V+ = +5V, V- = -25V, V _{OUT} = -10V | 1 | +25°C | 80 | - | dB |
| | | | 2, 3 | +125°C, -55°C | 74 | - | dB |
| | -CMRR | ΔV _{CM} = +10V, V+ = +25V, V- = -5V, V _{OUT} = +10V | 1 | +25°C | 80 | - | dB |
| | | | 2, 3 | +125°C, -55°C | 74 | - | dB |

Specifications HA-4741/883

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)

Device Tested at: $V_{SUPPLY} = \pm 15V$, $R_{SOURCE} = 100\Omega$, $R_{LOAD} = 500k\Omega$, $V_{OUT} = 0V$, Unless Otherwise Specified.

| PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUPS | TEMPERATURE | LIMITS | | UNITS |
|--------------------------------|----------------------|---------------------------------------------------------------------------------------------------------------------------|----------------------|---------------|--------|-----|-------|
| | | | | | MIN | MAX | |
| Output Voltage Swing | +V _{OUT1} | R _L = 10kΩ | 4 | +25°C | 12 | - | V |
| | | | 5, 6 | +125°C, -55°C | 12 | - | V |
| | -V _{OUT1} | R _L = 10kΩ | 4 | +25°C | - | -12 | V |
| | | | 5, 6 | +125°C, -55°C | - | -12 | V |
| | +V _{OUT2} | R _L = 2kΩ | 4 | +25°C | 10 | - | V |
| | | | 5, 6 | +125°C, -55°C | 10 | - | V |
| -V _{OUT2} | R _L = 2kΩ | 4 | +25°C | - | -10 | V | |
| | | 5, 6 | +125°C, -55°C | - | -10 | V | |
| Output Current | +I _{OUT} | V _{OUT} = -10V | 4 | +25°C | 5 | - | mA |
| | | | 5, 6 | +125°C, -55°C | 5 | - | mA |
| | -I _{OUT} | V _{OUT} = +10V | 4 | +25°C | - | -5 | mA |
| | | | 5, 6 | +125°C, -55°C | - | -5 | mA |
| Quiescent Power Supply Current | +I _{CC} | V _{OUT} = 0V, I _{OUT} = 0mA | 1 | +25°C | - | 5 | mA |
| | | | 2, 3 | +125°C, -55°C | - | 7 | mA |
| | -I _{CC} | V _{OUT} = 0V, I _{OUT} = 0mA | 1 | +25°C | -5 | - | mA |
| | | | 2, 3 | +125°C, -55°C | -7 | - | mA |
| Power Supply Rejection Ratio | +PSRR | ΔV _{SUP} = +5V, V ₊ = +10V, V ₋ = -15V, V ₊ = +20V, V ₋ = -15V | 1 | +25°C | 80 | - | dB |
| | | | 2, 3 | +125°C, -55°C | 80 | - | dB |
| | -PSRR | ΔV _{SUP} = -5V, V ₊ = +15V, V ₋ = -10V, V ₊ = +15V, V ₋ = -20V | 1 | +25°C | 80 | - | dB |
| | | | 2, 3 | +125°C, -55°C | 80 | - | dB |

TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Tested at: $V_{SUPPLY} = \pm 15V$, $R_{SOURCE} = 50\Omega$, $R_{LOAD} = 2k\Omega$, $C_{LOAD} = 50pF$, $A_{VCL} = +1V/V$, Unless Otherwise Specified.

| PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUPS | TEMPERATURE | LIMITS | | UNITS |
|---------------------------------------|----------------|--------------------------------------------------------------|----------------------|-------------|--------|-----|-------|
| | | | | | MIN | MAX | |
| Slew Rate | +SR | V _{OUT} = -5V to +5V | 7 | +25°C | 0.9 | - | V/μs |
| | -SR | V _{OUT} = +5V to -5V | 7 | +25°C | 0.9 | - | V/μs |
| Rise and Fall Time | T _R | V _{OUT} = 0 to +200mV 10% ≤ T _R ≤ 90% | 7 | +25°C | - | 140 | ns |
| | T _F | V _{OUT} = 0 to -200mV 10% ≤ T _F ≤ 90% | 7 | +25°C | - | 140 | ns |
| Overshoot | +OS | V _{OUT} = 0 to +200mV | 7 | +25°C | - | 40 | % |
| | -OS | V _{OUT} = 0 to -200mV | 7 | +25°C | - | 40 | % |
| Gain Bandwidth Product (Small Signal) | GBWP | V _{OUT} = 50mV | 7 | +25°C | 2.5 | - | MHz |

Specifications HA-4741/883

TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Characterized at: $V_{SUPPLY} = \pm 15V$, $R_{LOAD} = 5k\Omega$, $C_{LOAD} = 50pF$, Unless Otherwise Specified.

| PARAMETERS | SYMBOL | CONDITIONS | NOTES | TEMPERATURE | LIMITS | | UNITS |
|---------------------------------|-----------|----------------------------------------------------------------------------------------------------|-------|-----------------|--------|-----|------------|
| | | | | | MIN | MAX | |
| Differential Input Resistance | R_{IN} | $V_{CM} = 0V$ | 1 | +25°C | 260 | - | k Ω |
| Full Power Bandwidth | FPBW | $V_{PEAK} = 10V$ | 1, 2 | +25°C | 14 | - | kHz |
| Minimum Closed Loop Stable Gain | CLSG | $R_L = 2k\Omega$, $C_L = 50pF$ | 1 | -55°C to +125°C | 1 | - | V/V |
| Output Resistance | R_{OUT} | Open Loop | 1 | +25°C | - | 350 | Ω |
| Quiescent Power Consumption | PC | $V_{OUT} = 0V$, $I_{OUT} = 0mA$ | 1, 3 | -55°C to +125°C | - | 180 | mW |
| Channel Separation | CS | $f = 10kHz$, $R_S = 1k\Omega$ Referred to Input $A_V = 100V/V$, $V_{IN} = 100mV_{PEAK}$ | 1 | +25°C | -66 | - | dB |

NOTES:

- Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.
- Full Power Bandwidth guarantee based on Slew Rate measurement using $FPBW = Slew\ Rate / (2\pi V_{PEAK})$.
- Quiescent Power Consumption based upon Quiescent Supply Current test maximum. (No load on outputs.)

TABLE 4. ELECTRICAL TEST REQUIREMENTS

| MIL-STD-883 TEST REQUIREMENTS | SUBGROUPS (SEE TABLES 1 AND 2) |
|---------------------------------------------|--------------------------------|
| Interim Electrical Parameters (Pre Burn-In) | 1 |
| Final Electrical Test Parameters | 1 (Note 1), 2, 3, 4, 5, 6, 7 |
| Group A Test Requirements | 1, 2, 3, 4, 5, 6, 7 |
| Groups C and D Endpoints | 1 |

NOTE:

- PDA applies to Subgroup 1 only.

HA-4741/883

Die Characteristics

DIE DIMENSIONS:

87 x 75 x 19 mils \pm 1 mils
2210 x 1910 x 483 μ m \pm 25.4 μ m

METALLIZATION:

Type: Al, 1% Cu
Thickness: 16k \AA \pm 2k \AA

GLASSIVATION:

Type: Nitride
Thickness: 7k \AA \pm 0.7k \AA

WORST CASE CURRENT DENSITY:

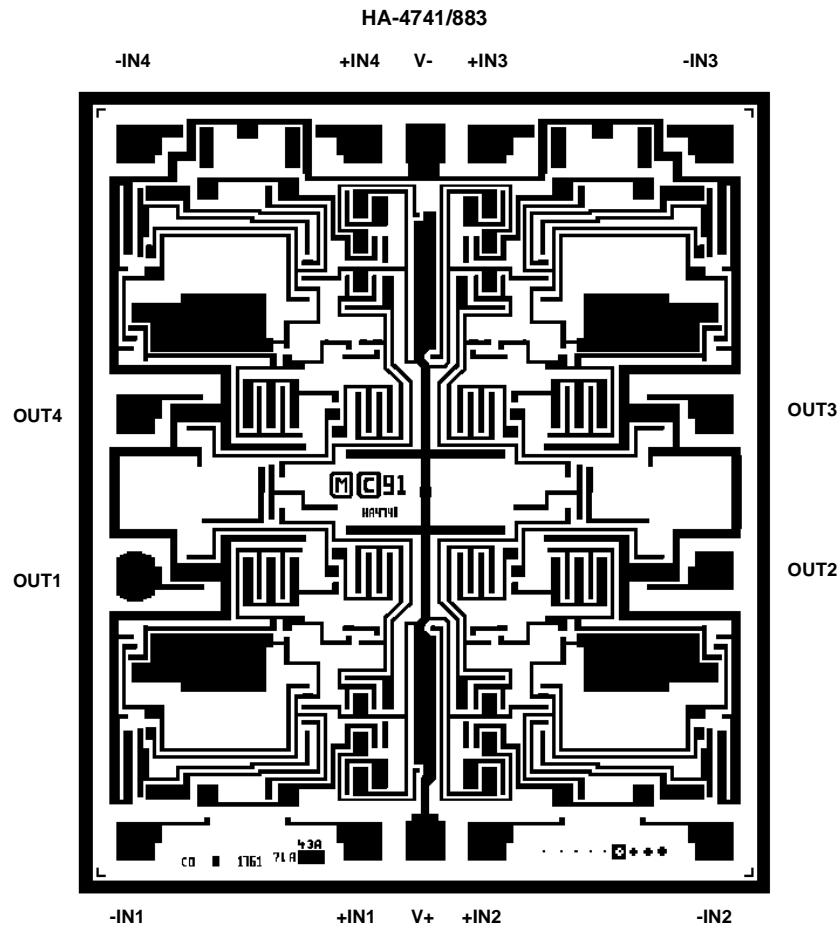
1.68 x 10⁵ A/cm²

SUBSTRATE POTENTIAL (Powered Up): V-

TRANSISTOR COUNT: 72

PROCESS: Junction Isolated Bipolar/JFET

Metallization Mask Layout



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